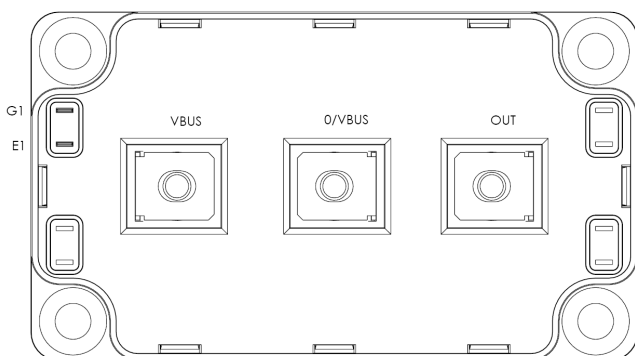
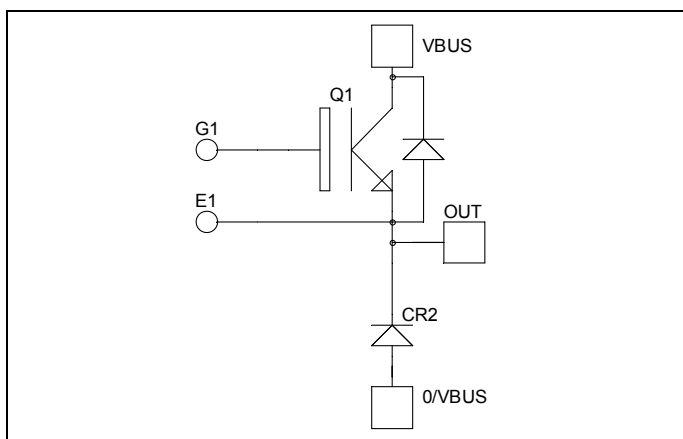


## Buck chopper NPT IGBT Power Module

$V_{CES} = 600V$   
 $I_C = 350A @ T_c = 80^\circ C$



### Application

- AC and DC motor control
- Switched Mode Power Supplies

### Features

- Non Punch Through (NPT) Fast IGBT
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 100 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

### Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS compliant

### Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage	600	V
$I_C$	Continuous Collector Current	$T_c = 25^\circ C$	A
		$T_c = 80^\circ C$	
$I_{CM}$	Pulsed Collector Current	$T_c = 25^\circ C$	1225
$V_{GE}$	Gate - Emitter Voltage	$\pm 20$	V
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$	1562
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^\circ C$	800A @ 600V



**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

**All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified**

**Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0\text{V}$ $V_{CE} = 600\text{V}$	$T_j = 25^\circ\text{C}$		200	$\mu\text{A}$
			$T_j = 125^\circ\text{C}$		1750	
$V_{CE(sat)}$	Collector Emitter saturation Voltage	$V_{GE} = 15\text{V}$ $I_C = 360\text{A}$	$T_j = 25^\circ\text{C}$	2.0	2.5	V
			$T_j = 125^\circ\text{C}$	2.2		
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 4\text{mA}$	3		5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = \pm 20\text{V}, V_{CE} = 0\text{V}$			$\pm 300$	nA

**Dynamic Characteristics**

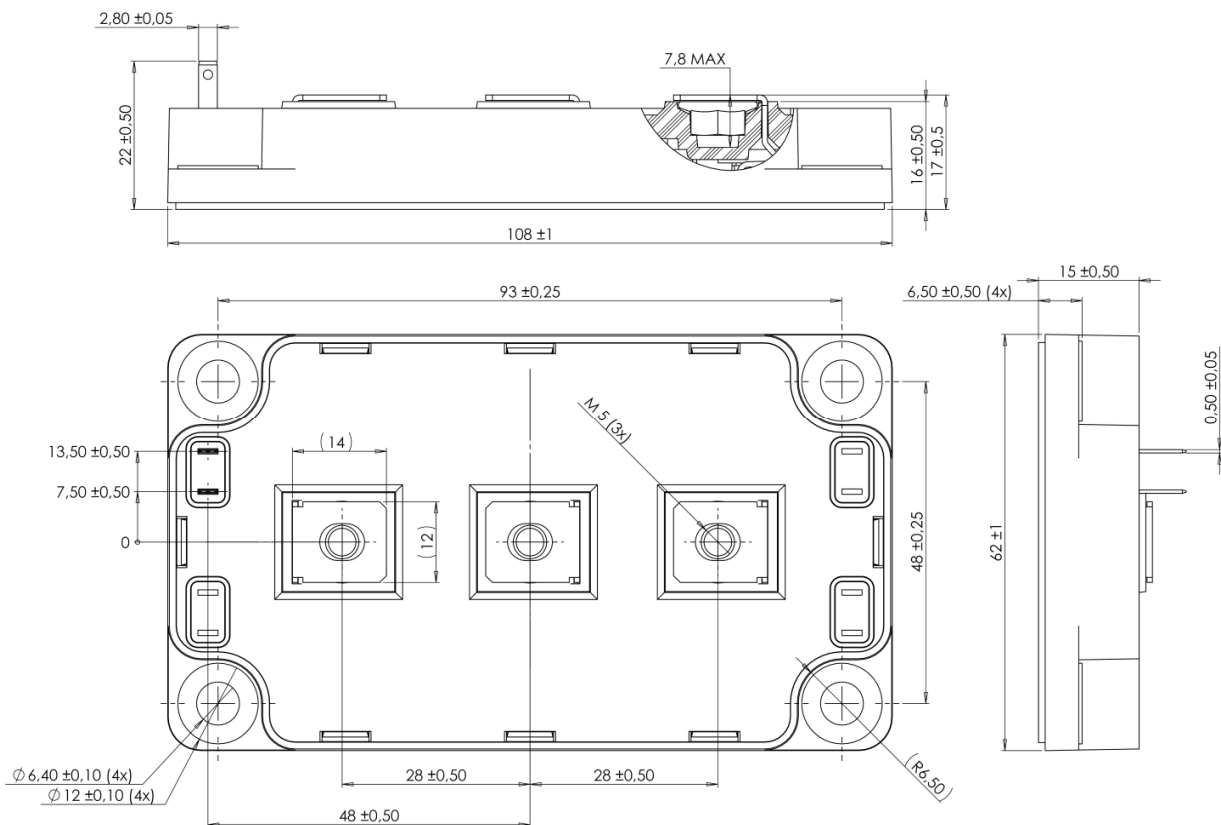
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{ies}$	Input Capacitance	$V_{GE} = 0\text{V}$		17.2		nF
$C_{oes}$	Output Capacitance	$V_{CE} = 25\text{V}$		1.88		
$C_{res}$	Reverse Transfer Capacitance	$f = 1\text{MHz}$		1.6		
$Q_g$	Total gate Charge	$V_{GE} = 15\text{V}$		1320		nC
$Q_{ge}$	Gate – Emitter Charge	$V_{Bus} = 300\text{V}$		1160		
$Q_{gc}$	Gate – Collector Charge	$I_C = 360\text{A}$		800		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ( $25^\circ\text{C}$ )		26		ns
$T_r$	Rise Time	$V_{GE} = 15\text{V}$		25		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 400\text{V}$		150		
$T_f$	Fall Time	$I_C = 360\text{A}$ $R_G = 1.25\Omega$		30		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ( $125^\circ\text{C}$ )		26		ns
$T_r$	Rise Time	$V_{GE} = 15\text{V}$		25		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 400\text{V}$		170		
$T_f$	Fall Time	$I_C = 360\text{A}$ $R_G = 1.25\Omega$		40		
$E_{on}$	Turn-on Switching Energy	$V_{GE} = 15\text{V}$ $V_{Bus} = 400\text{V}$	$T_j = 125^\circ\text{C}$	17.2		mJ
$E_{off}$	Turn-off Switching Energy	$I_C = 360\text{A}$ $R_G = 1.25\Omega$	$T_j = 125^\circ\text{C}$	14		

**Chopper diode ratings and characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		600			V
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 600\text{V}$	$T_j = 25^\circ\text{C}$		750	$\mu\text{A}$
			$T_j = 125^\circ\text{C}$		1500	
$I_F$	DC Forward Current	$T_c = 80^\circ\text{C}$		400		A
$V_F$	Diode Forward Voltage	$I_F = 400\text{A}$		1.6	1.8	V
		$I_F = 800\text{A}$		1.9		
		$I_F = 400\text{A}$ $T_j = 125^\circ\text{C}$		1.4		
$t_{rr}$	Reverse Recovery Time	$I_F = 400\text{A}$ $V_R = 400\text{V}$	$T_j = 25^\circ\text{C}$	180		ns
		$di/dt = 800\text{A}/\mu\text{s}$	$T_j = 125^\circ\text{C}$	220		
$Q_{rr}$	Reverse Recovery Charge	$di/dt = 800\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$	1560		nC
			$T_j = 125^\circ\text{C}$	5800		

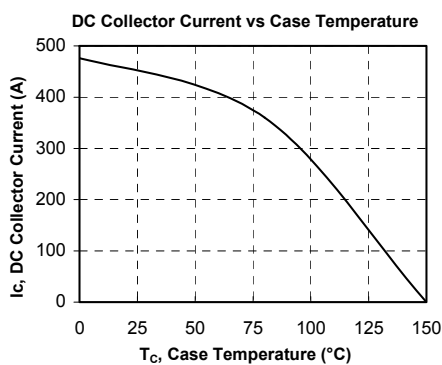
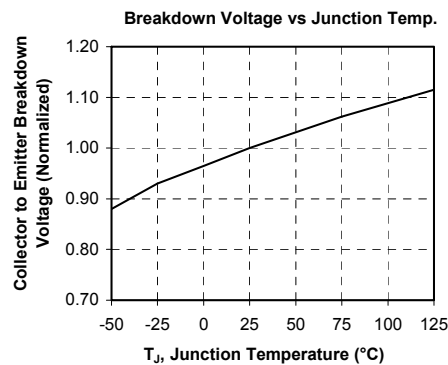
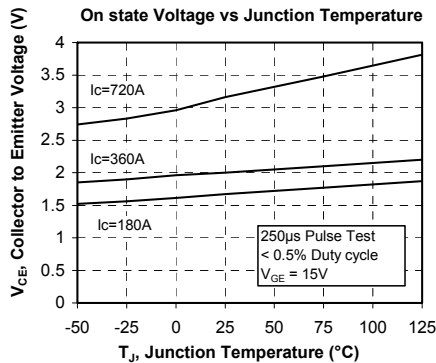
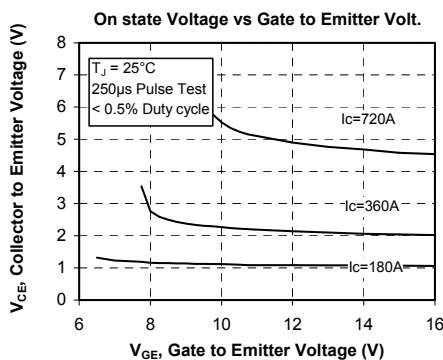
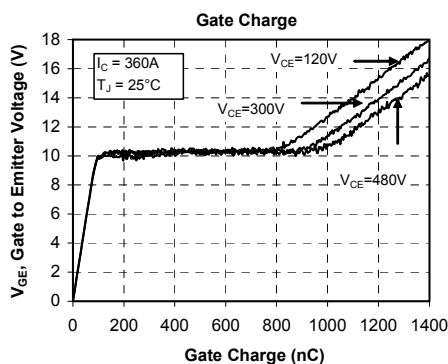
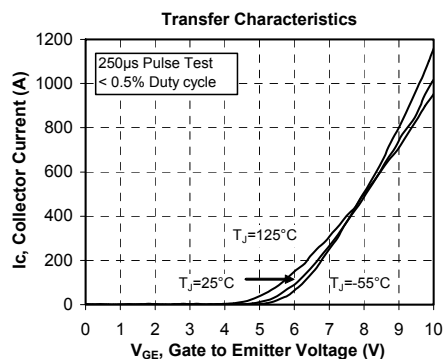
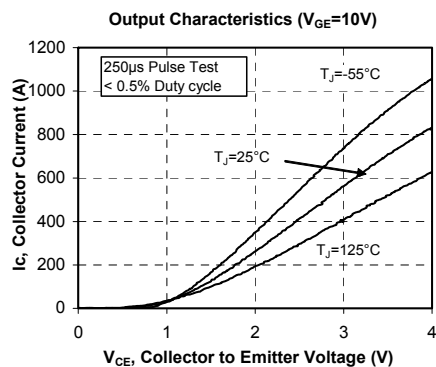
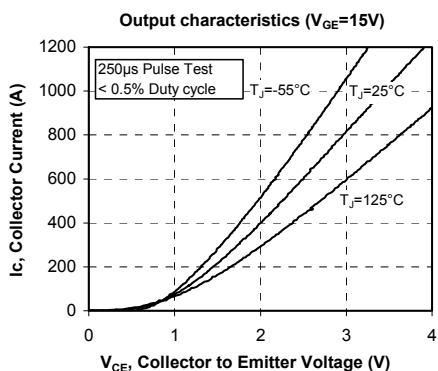
**Thermal and package characteristics**

Symbol	Characteristic		Min	Typ	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance	IGBT			0.08	°C/W
		Diode			0.16	
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz		4000			V
T <sub>J</sub>	Operating junction temperature range		-40		150	°C
T <sub>STG</sub>	Storage Temperature Range		-40		125	
T <sub>C</sub>	Operating Case Temperature		-40		100	
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package Weight				300	g

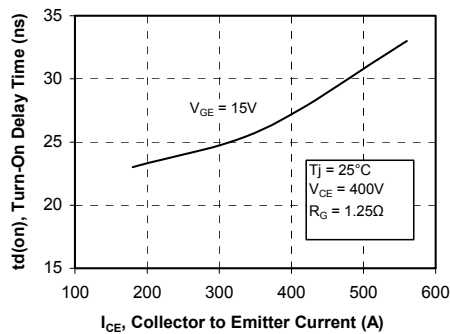
**SP6 Package outline (dimensions in mm)**


See application note APT0601 - Mounting Instructions for SP6 Power Modules on [www.microsemi.com](http://www.microsemi.com)

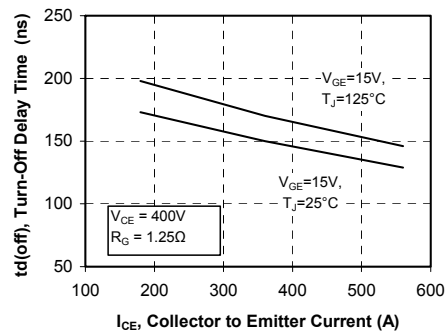
## Typical Performance Curve



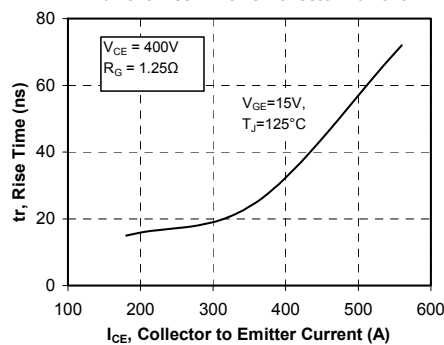
Turn-On Delay Time vs Collector Current



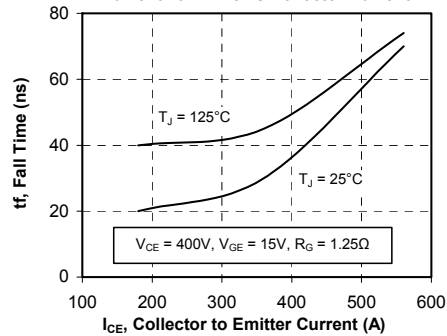
Turn-Off Delay Time vs Collector Current



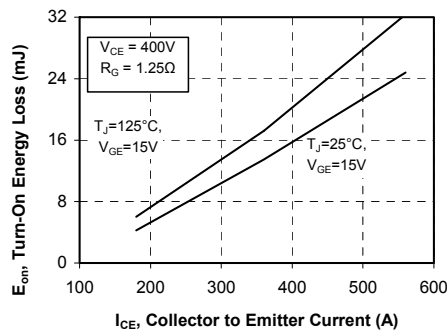
Current Rise Time vs Collector Current



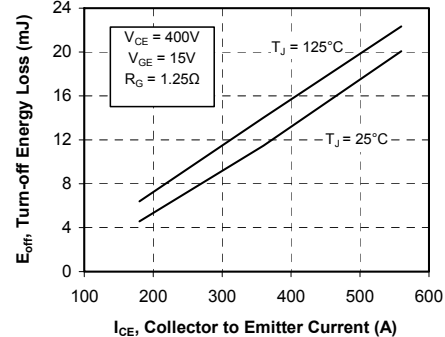
Current Fall Time vs Collector Current



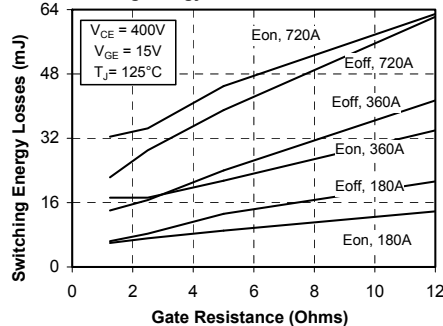
Turn-On Energy Loss vs Collector Current



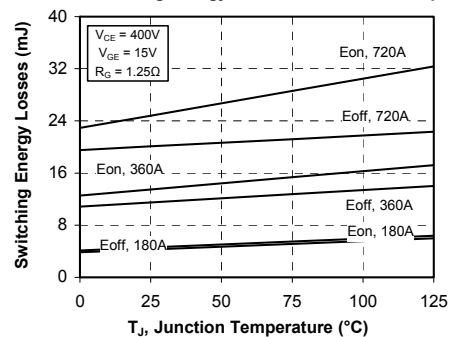
Turn-Off Energy Loss vs Collector Current

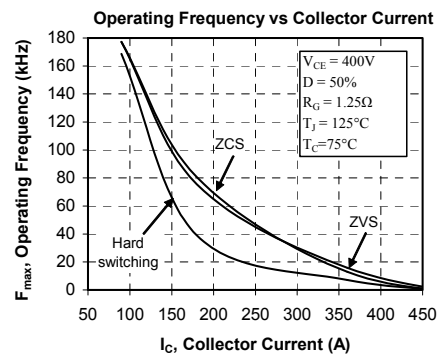
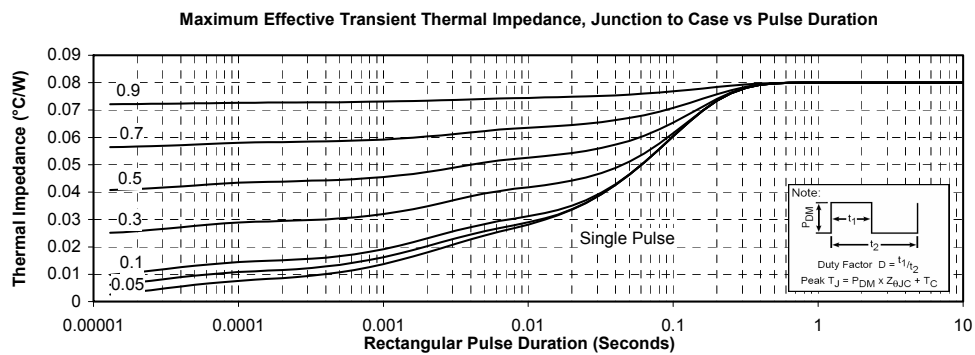
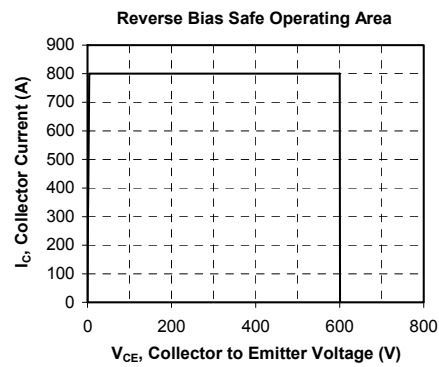
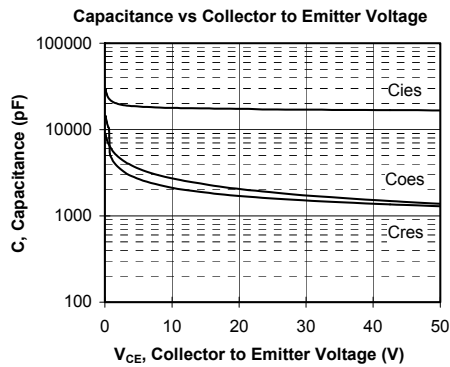


Switching Energy Losses vs Gate Resistance



Switching Energy Losses vs Junction Temp.





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